

# **Subminiature Photointerrupter**

## **Model No: LBT-140**

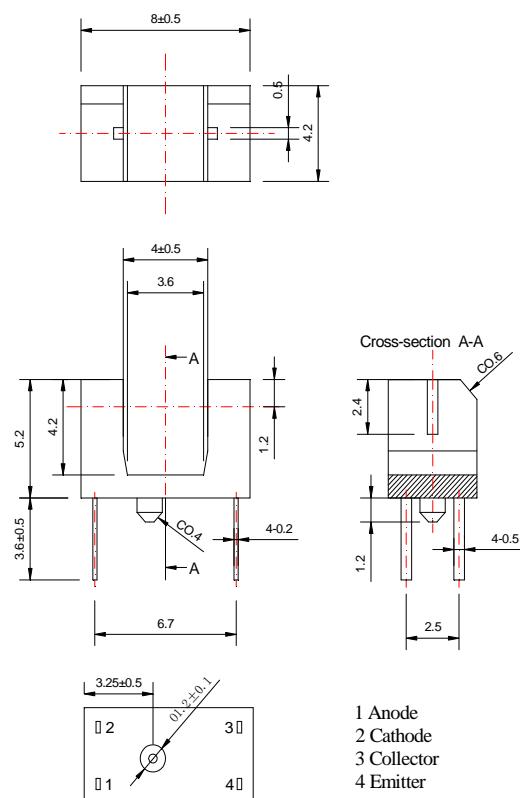
### **Features**

- Compact package based on the double-mold method.
- High resolution (slit width = 0.5mm).
- Gap between emitter and detector is 4.0mm.

### **Applications**

- Floppy disk drives
- Printers
- Cameras

Outline Dimensions (Unit: mm)



1 Anode  
2 Cathode  
3 Collector  
4 Emitter

## Subminiature Photointerrupter

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Absolute Maximum Ratings (Ambient Temperature: 25°C)

Item	Symbol	Rating	Units	Note
Input	Forward current	IF	50	mA
	Reverse voltage	VR	5	V
	Power dissipation	PD	80	mW
Output	Collector-emitter voltage	Vceo	30	V
	Emitter-collector voltage	Veco	4.5	V
	Collector current	Ic	30	mA
	Collector power dissipation	PC	80	mW
Storage Temperature	Tstg	-40 to +100	°C	
Operating Temperature	Top	-25 to +85	°C	
Soldering Temperature	Tsol	260	°C	10 seconds max.

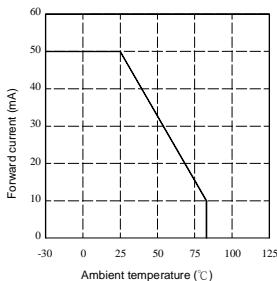
Electrical Specifications (Ambient Temperature: 25°C)

Item	Symbol	Min.	Typ.	Max.	Units	Conditions
Input	Forward voltage	VF		1.3	1.6	V IF=50mA
	Peak forward voltage	VFM		3	4	V IFM=0.5A
	Reverse current	IR			10	μA VR=5V
Output	Collector dark current	Iceo			0.5	μA Vce=10V
	Collector-emitter breakdown voltage	BVceo	30			V Ic=50μA
	Emitter-collector breakdown voltage	BVeco	4.5			V Iec=50μA
Combination	Collector current	Ic	0.2	0.55	mA	Vce=5V, IF=20mA
	Collector-emitter saturation voltage	Vce(sat)			0.4	V If=20mA, Ic=0.1A
	Response time	Tr/tf		10	μs	If=5mA, Vcc=5V, RL=100Ω
Infrared light emitter diode	Cut-off frequency	fc		1	MHz	If=50mA
	Peak light emitting wavelength	λP		950	nm	
Photo transistor	Response time	Tr/tf		10	μs	Vcc=5V, Ic=1mA, RL=100Ω
	Maximum sensitivity wavelength	λP		800	nm	

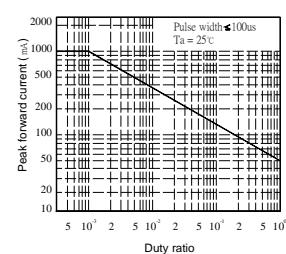
# Subminiature Photointerrupter

## Reference Data

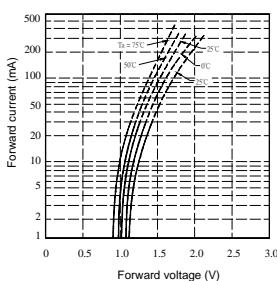
Forward current Vs.  
Ambient temperature



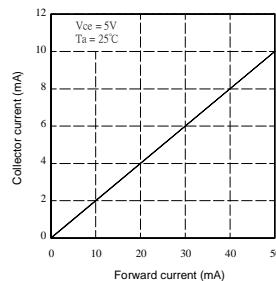
Peak forward current Vs.  
Duty ratio



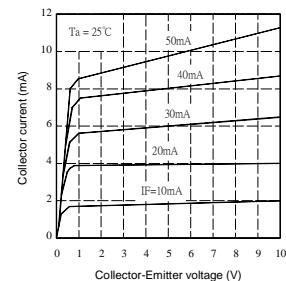
Forward current Vs.  
Forward voltage



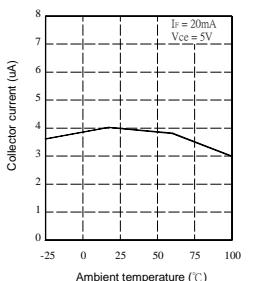
Collector current Vs.  
Forward current



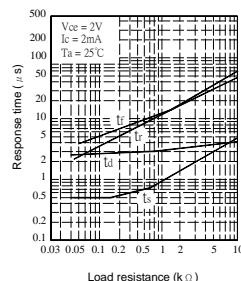
Collector current Vs.  
Collector-Emitter voltage



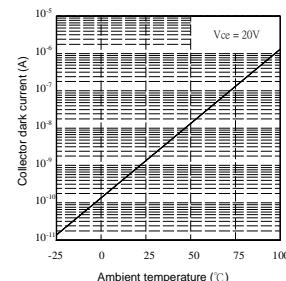
Collector current Vs.  
Ambient temperature



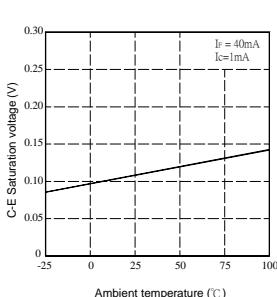
Response time Vs.  
Load resistance



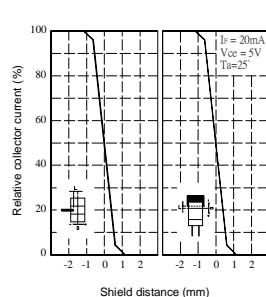
Collector dark current Vs.  
Ambient temperature



C-E Saturation voltage Vs.  
Ambient temperature



Relative collector current Vs.  
Shield distance



Test circuit for response time

